

Vishay Semiconductors

High Speed Optocoupler, 1 MBd, Transistor Output



DESCRIPTION

The SFH6315T, SFH6316T, SFH6343T, high speed optocouplers, each consists of a GaAlAs infrared emitting diode, optically coupled with an integrated photo detector and a high speed transistor. The photo detector is junction isolated from the transistor to reduce miller capacitance effects. The open collector output function allows circuit designers to adjust the load conditions when interfacing with different logic systems such as TTL, CMOS, etc.

Because the SFH6343T has a faraday shield on the detector chip, it can also reject and minimize high input to output common mode transient voltages. There is no base connection, further reducing the potential electrical noise entering the package.

The SFH6315T, SFH6316T, SFH6343T are packaged in industry standard SOIC-8 packages and are suitable for surface mounting.

FEATURES

- Surface mountable
- Industry standard SOIC-8 footprint
- Compatible with infrared vapor phase reflow and wave soldering processes
- Isolation test voltage, 4000 V_{RMS}
- Very high common mode transient immunity: 15000 V/ μ s at V_{CM} = 1500 V guaranteed (SFH6343)
- High speed: 1 MBd
- TTL compatible
- \bullet Guaranteed AC and DC performance temperature: 0 °C to 70 °C
- Open collector output
- Pin compatible with agilent (HP) optocouplers
 - SFH6315T HCPL0500
 - SFH6316T HCPL0501
 - SFH6343T HCPL0453
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC

APPLICATIONS

- Line receivers
- Logic ground isolation
- Analog signal ground isolation
- Replace pulse transformers

AGENCY APPROVALS

- UL1577, file no. E52744 system code Y
- cUL file no. E52744, equivalent to CSA bulletin 5A
- DIN EN 60747-5-5 (VDE 0884) available with option 1

ORDERING INFORMATIO	N		
S F H		# # Т	SIOC-8
AGENCY CERTIFIED/ PACKAGE	PART NUMBER	CTR (%)	<u> </u>
	. F		
UL, cUL	≥ 5	≥ 15	NO BASE CONNECTION
SOIC-8	SFH6315T ⁽¹⁾	SFH6316T ⁽¹⁾	SFH6343T ⁽¹⁾

Note

⁽¹⁾ Also available in tubes; do not add T to end

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	VALUE	UNIT					
INPUT								
Reverse voltage		V _R	3	V				
DC forward current		I _F	25	mA				
Surge forward current	t _p ≤ 1 μs, 300 pulses/s	I _{FSM}	1	A				
Power dissipation	T _{amb} ≤ 70 °C	P _{diss}	45	mW				



RoHS

COMPLIANT





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ABSOLUTE MAXIMUM RATINGS	S (T _{amb} = 25 °C, unless otherwise sp	pecified)		
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
OUTPUT				
Supply voltage		Vs	- 0.5 to 30	V
Output voltage		Vo	- 0.5 to 25	V
Output current		Ι _Ο	8	mA
Power dissipation	T _{amb} ≤ 70 °C	P _{diss}	100	mW
COUPLER				
Isolation test voltage between emitter and detector		VISO	4000	V _{RMS}
Pollution degree (DIN VDE 0110)			2	
Creepage distance			≥4	mm
Clearance distance			≥4	mm
Comparative tracking index per DIN IEC 112/VDE 0303 part 1		CTI	175	
Isolation resistance	$V_{IO} = 500 \text{ V}, \text{ T}_{amb} = 25 \text{ °C}, \text{ R}_{ISOL}$ ⁽¹⁾	R _{IO}	≥ 10 ¹²	Ω
Isolation resistance	$V_{IO} = 500 \text{ V}, \text{ T}_{amb} = 100 ^{\circ}\text{C}, \text{ R}_{ISOL} ^{(1)}$	R _{IO}	≥ 10 ¹¹	Ω
Storage temperature range		T _{stg}	- 55 to + 150	°C
Ambient temperature range		T _{amb}	- 55 to + 100	°C
Junction temperature		Tj	100	°C
Soldering temperature ⁽²⁾	max. 10 s, dip soldering distance to seating plane ≥ 1.5 mm	·	260	°C

Notes

• Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.

⁽¹⁾ Device considered a two-terminal device: pins 1, 2, 3, and 4 shorted together and pins 5, 6, 7, and 8 shorted together.

⁽²⁾ Refer to reflow profile for soldering conditions for surface mounted devices.

ELECTRICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)									
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT		
INPUT	<u>.</u>						•		
Forward voltage	l⊧ = 16 mA. 25 °C		V _F		1.6	1.8	V		
i orward voltage	if = 10 mA, 20 0	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	V						
Reverse current	V _R = 3 V		I _R		0.5	10	μA		
Capacitance	$f = 1 MHz, V_F = 0 V$		C _{IN}		75		pF		
Temperature coefficient of	I _F = 16 mA		$\Delta V_{F}/$		- 1.7		mW/°C		
OUTPUT									
Logic low supply current	I_F = 16 mA, V_O = open, V_{CC} = 15 V		I _{CCL}		200		μA		
Logic high supply current	$I_F = 0 \text{ mA}, V_O = \text{open}, V_{CC} = 15 \text{ V};$		I _{CCH}		0.001	1	μA		
Logic high supply current	25 °C		I _{CCH}		0.001	10 10 7 1 1 2 5 0.4 5 0.4 5 0.5 5 0.4 5 0.5	μA		
	$I_F = 16 \text{ mA}, V_{CC} = 4.5 \text{ V}, I_O = 1.1 \text{ mA},$	SFH6315T	V _{OL}		0.15	0.4	V		
	I_F = 16 mA, V_{CC} = 4.5 V, I_O = 0.8 mA	SFH6315T	V _{OL}		0.15	0.5	V		
Logic low output voltage	$I_F = 16 \text{ mA}, V_{CC} = 4.5 \text{ V}, I_O = 3 \text{ mA},$	SFH6316T	V _{OL}		0.15	0.4	V		
Logic low output voltage	$I_F = 16 \text{ mA}, V_{CC} = 4.5 \text{ V}, I_O = 2.4 \text{ mA}$	SFH6343T	V _{OL}		0.15	0.5	V		
	$I_F = 16 \text{ mA}, V_{CC} = 4.5 \text{ V}, I_O = 2.4 \text{ mA}$	SFH6316T	V _{OL}		0.15	0.5	V		
	I_F = 16 mA, V_{CC} = 4.5 V, I_O = 2.4 mA	SFH6343T	V _{OL}		0.15	0.5	V		
	$I_F = 0 \text{ mA}, V_O = V_{CC} = 5.5 \text{ V}, 25 \text{ °C}$		I _{OH}		0.003	0.5	μA		
Logic high output current	$I_F = 0 \text{ mA}, V_O = V_{CC} = 15 \text{ V}, 25 \text{ °C}$		I _{OH}		0.01	1	μA		
	$I_F = 0 \text{ mA}, V_O = V_{CC} = 15 \text{ V}$		I _{OH}			50	μA		



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ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)								
PARAMETER	METER TEST CONDITION PART SYMBOL MIN. TYP. MAX. UNIT							
COUPLER								
Capacitance (input to output) (1)	f = 1 MHz		C _{IO}		0.4		pF	

Notes

⁽¹⁾ A 0.1 µF bypass capacitor connected between pins 5 and 8 is recommended.

CURRENT TRANSFER RATIO									
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT		
	$V_{O} = 0.4 \text{ V}, \text{ I}_{F} = 16 \text{ mA}, \text{ V}_{CC} = 4.5 \text{ V}, 25 \text{ °C}$	SFH6315T	CTR	7	16	50	%		
	$V_{O} = 0.5 \text{ V}, I_{F} = 16 \text{ mA}, V_{CC} = 4.5 \text{ V}$	SFH6315T	CTR	5	17		%		
Current transfer ratio	$V_{O} = 0.4 \text{ V}, \text{ I}_{F} = 16 \text{ mA}, \text{ V}_{CC} = 4.5 \text{ V}, 25 \text{ °C}$	SFH6316T	CTR	19	35	50	%		
	$V_{O} = 0.4 \text{ V}, I_{F} = 16 \text{ mA}, V_{CC} = 4.5 \text{ V}, 25 \text{ °C}$	SFH6343T	CTR	19	35	50	%		
	$V_{O} = 0.5 \text{ V}, I_{F} = 16 \text{ mA}, V_{CC} = 4.5 \text{ V}$	SFH6343T	CTR	15	36		%		
	$V_{O} = 0.5 \text{ V}, I_{F} = 16 \text{ mA}, V_{CC} = 4.5 \text{ V}$	SFH6316T	CTR	15	36		%		

Note

Current transfer ratio in percent equals the ratio of output collector current (I_O) to the forward LED input current (I_F) times 100. ٠ A 0.1 µF bypass capacitor connected between pins 5 and 8 is recommended.



Fig. 1 - Test Circuit for Switching Times

SWITCHING CHARACTERISTICS								
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Propagation delay time to logic low at output (see fig. 1)	R _L = 4.1 KΩ	SFH6315T	t _{PHL} ⁽¹⁾		0.5	1.5	μs	
		SFH6315T	t _{PHL}		0.5	2	μs	
	R _L = 1.9 KΩ	SFH6316T	t _{PHL}		0.25	0.8	μs	
		SFH6343T	t _{PHL}		0.25	1	μs	
Propagation delay time to logic high at output (see fig. 1)	R _L = 4.1 KΩ	SFH6315T	t _{PLH} ⁽¹⁾		0.5	1.5	μs	
		SFH6315T	t _{PLH}		0.5	2	μs	
		SFH6316T	t _{PLH}		0.5	0.8	μs	
	$R_L = 1.9 \text{ K}\Omega$	SFH6343T	t _{PLH}		0.5	1	μs	

Notes

Over recommended temperature (T_{amb} = 0 °C to 70 °C), V_{CC} = 5 V, I_F = 16 mA unless otherwise specified. The 1.9 kW load represents 1 TTL unit load of 1.6 mA and the 5.6 kW pull-up resistor. .

The 4.1 kW load represents 1 LSTTL unit load of 0.36 mA and the 6.1 kW pull-up resistor.

⁽¹⁾ $T_{amb} = 25$ °C, unless otherwise specified.

Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering • evaluation. Typical values are for information only and are not part of the testing requirements.

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COMMON MODE TRANSIENT IMMUNITY								
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Common mode transient immunity at logic high level output (see fig. 2)	$\label{eq:RL} \begin{split} R_{L} = 4.1 \ k\Omega, \ I_{F} = 0 \ mA, \\ V_{CM} = 10 \ V_{P\text{-}P} \end{split}$	SFH6315T	CM _H		1		kV/µs	
		SFH6316T	CM _H		1		kV/µs	
		SFH6343T	CM _H	15	30		kV/µs	
Common mode transient immunity at logic low level output (see fig. 2)	$\label{eq:RL} \begin{split} R_L = 4.1 \ k\Omega, \ I_F = 16 \ mA, \\ V_{CM} = 10 \ V_{P\text{-}P} \end{split}$	SFH6315T	CM _L		1		kV/µs	
	$\label{eq:RL} \begin{split} R_L = 1.9 \ k\Omega, \ I_F = 16 \ mA, \\ V_{CM} = 10 \ V_{P\text{-}P} \end{split}$	SFH6316T	CML		1		kV/µs	
		SFH6343T	CM _L	15	30		kV/µs	

Note

• Common mode transient immunity in a logic high level is the maximum tolerable (positive) dV_{CM}/dt on the leading edge of the common mode pulse (V_{CM}) to assure that the output will remain in a logic high state (i.e., $V_0 > 2$ V). Common mode transient immunity in a logic low level the maximum tolerable (negative) dV_{CM}/dt on the trailing edge of the common mode pulse signal (V_{CM} to assure that the output will remain in logic low state, i.e., $V_0 > 0.8$ V).

The 1.9 k Ω load represents 1 TTL unit load of 1.6 mA and the 5.6 k Ω pull-up resistor.

The 4.1 k\Omega load represents 1 LSTTL unit load of 0.36 mA and the 6.1 k\Omega pull-up resistor.



Fig. 2 - Test Circuit for Transient Immunity and Typical Waveforms

SAFETY AND INSULATION RATINGS									
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT			
Climatic Classification (according to IEC 68 part 1)				55/100/21					
Comparative Tracking Index		СТІ	175		399				
V _{IOTM}			6000			V			
V _{IORM}			560			V			
P _{SO}					350	mW			
I _{SI}					150	mA			
T _{SI}					165	°C			
Creepage distance			4			mm			
Clearance distance			4			mm			
Insulation thickness			0.2			mm			

Note

• As per IEC 60747-5-5, §7.4.3.8.1, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.



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TYPICAL CHARACTERISTICS (Tamb = 25 °C, unless otherwise specified)



Fig. 3 - LED Forward Current vs. Forward Voltage



Fig. 4 - Permissible Forward LED Current vs. Temperature



Fig. 5 - Permissible Power Dissipation vs. Temperature



Fig. 6 - Output Current vs. Temperature



SFH6316T and SFH6343T



Fig. 8 - Propagation Delay vs. Temperature SFH6315T

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Fig. 9 - Logic High Output Current vs.Temperature

PACKAGE DIMENSIONS in millimeters



PACKAGE MARKING





Fig. 10 - Small Signal Current Transfer Ratio vs. Input Current





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